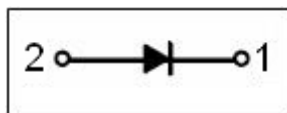


Rev.J Jan.-2019

SOD-323 M M æ M 4 ~ || 1
 Silicon Diode in a SOD-323 Plastic Package.

Ã H y ð ñ f ß
 Fast switching diodes. HF Product.

£ ¢ n 3 N J n
 Small signal diode.

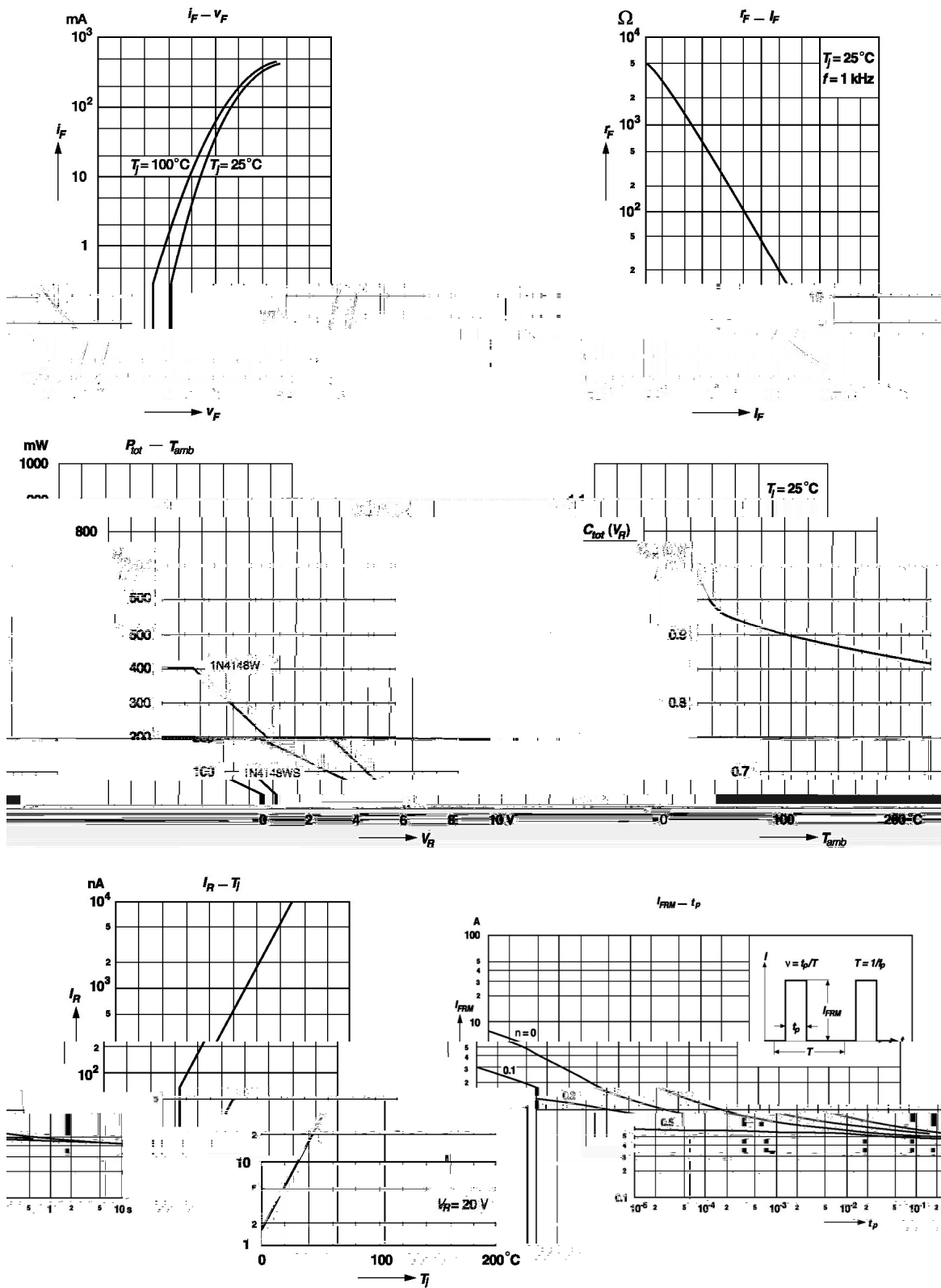


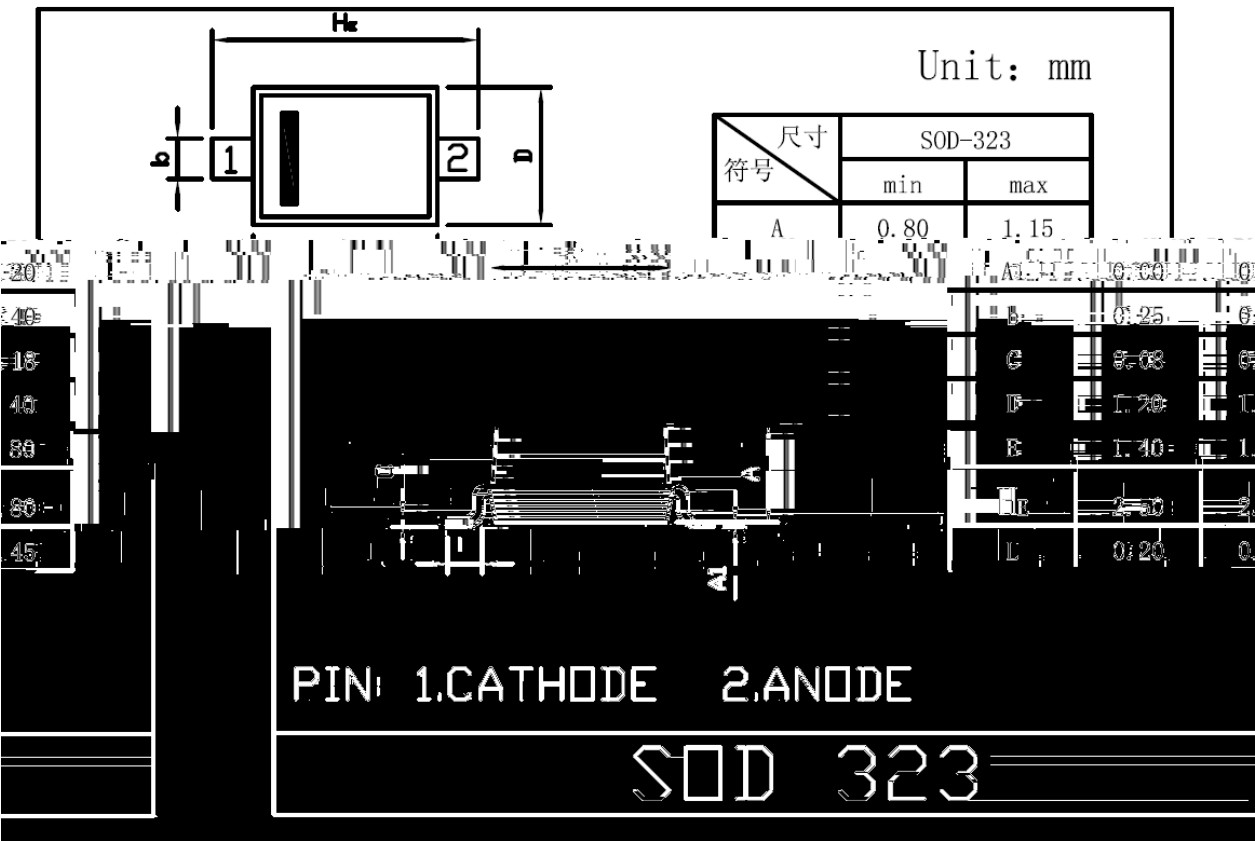
PIN1:Cathode PIN2:Anode

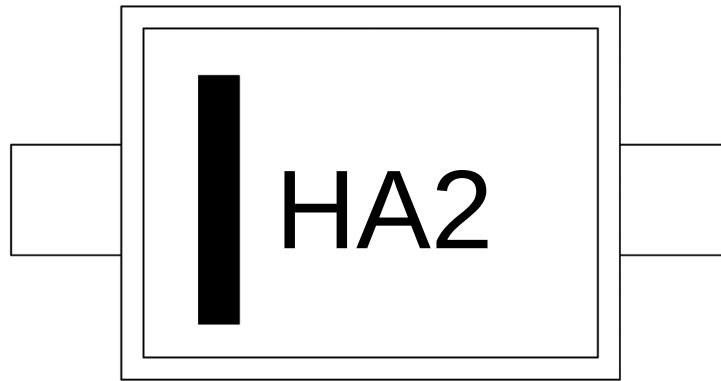
Marking	HA2
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Parameter	Symbol	Rating	Unit
Reverse Voltage	V_R	75	V
Peak Reverse Voltage	V_{RM}	100	V
Average Rectified Output Current	I_O	150	mA
Forward Continuous Current	I_{FM}	300	mA
Non-Repetitive Peak Forward Surge Current	$I_{FSM} (t=1.0\mu s)$	2.0	A
	$I_{FSM} (t=1.0s)$	1.0	A
Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	625	/W

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=10mA$			1.0	V
Instantaneous Reverse Current	I_R	$V_R=20V$			25	nA
		$V_R=75V$			5	μA
		$V_R=20V \quad T_j=150^\circ C$			50	μA
Capacitance	C_{tot}	$V_F=V_R=0V$			4	pF
Reverse Recovery Time	t_{rr}	$I_F=10mA \quad V_R=6.0V$ $I_R=1mA \quad R_L=100\Omega$			4	ns
Voltage Rise when Switching On tested	V_{fr}	$t_p=0.1\mu s \quad f_p=5to100kHz$ Time<30ns			2.5	V
Total Capacitance	C_T	$V_R=0 \quad f=1.0MHz$			2.0	pF







” X

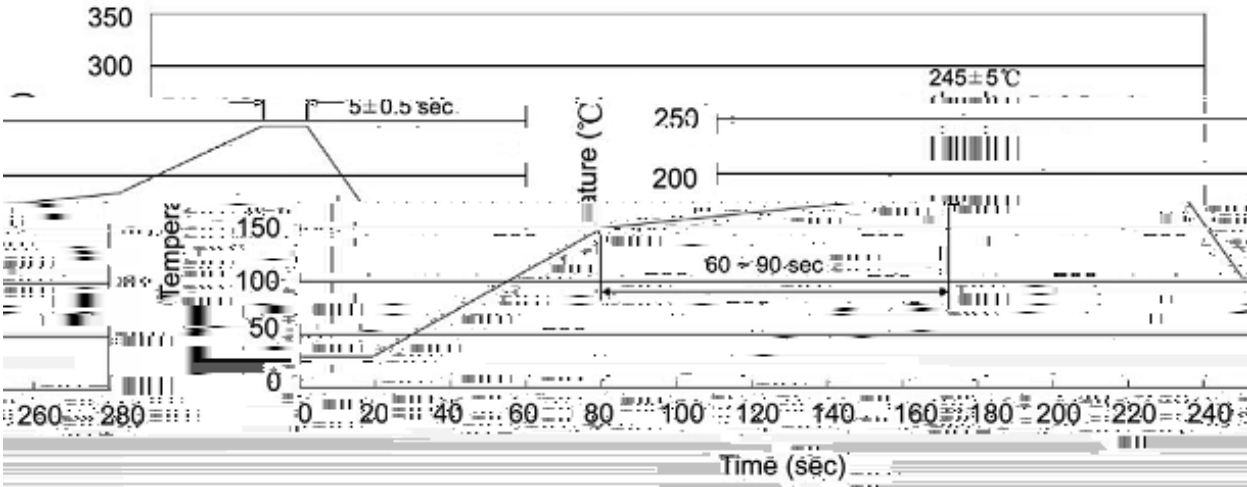
K X ㄟ 3 〃 ㄢ

D5 X ㄟ 3 〃 ㄢ

Note:

H: Company Code.

A2: Product Type.



- ” X
1. 150~180 ℃ 60~90sec;
 2. 245±5℃ 5±0.5sec;
 3. 2~10 ℃/sec.

- Note:
- 1.Preheating:150~180 ℃ , Time:60~90sec.
 - 2.Peak Temp.:245±5 ℃ , Duration:5±0.5sec.
 3. Cooling Speed: 2~10 ℃/sec.

260±5℃ 10±1 sec. Temp.:260±5℃ Time:10±1 sec

REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱
						"		